

P Channel Enhancement Mode MOSFET
- 10A

DESCRIPTION

The STP4407 is the P-Channel logic enhancement mode power field effect transistor is produced using high cell density, DMOS J05

STP4407

ELECTRICAL CHARACTERISTICS (Ta = 25°C Unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-30			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.0		-2.5	V
Gate Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS} $T_J=55^\circ C$	$V_{DS}=-30V, V_{GS}=0V$			-1	uA
		$3V_{DS}=-30V, V_{GS}=0V$			-5	
Drain-source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-10A$		15	20	mΩ
		$V_{GS}=-4.5V, I_D=-6.0A$		24	32	
Forward Transconductance	gfs	$V_{DS}=-5V, I_D=-10A$		26		S

Diode Forward Voltage V_{SD} $I_S=-12$ 444.32 Tc 144 -1.44 ref410.64 606.56 () J330.490.0487
V

TYPICAL CHARACTERISTICS

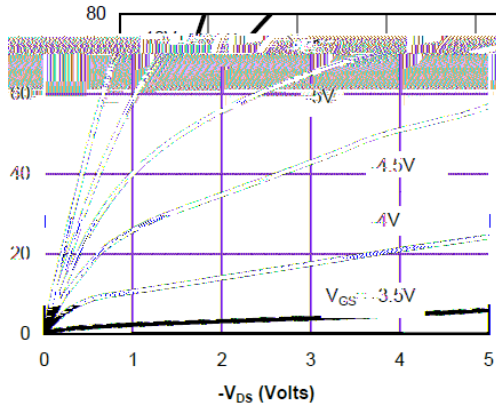


Figure 1: On-Region Characteristics

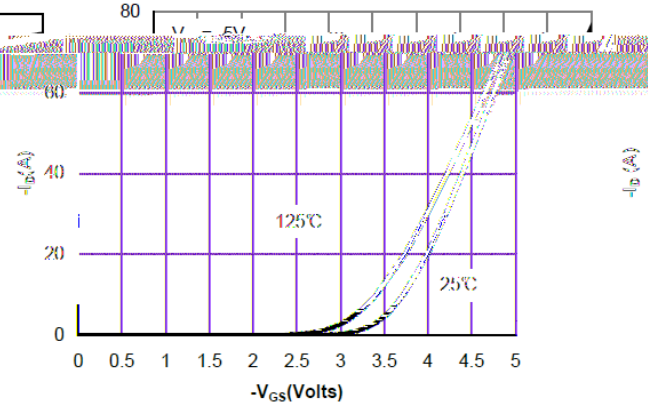


Figure 2: Transfer Characteristics

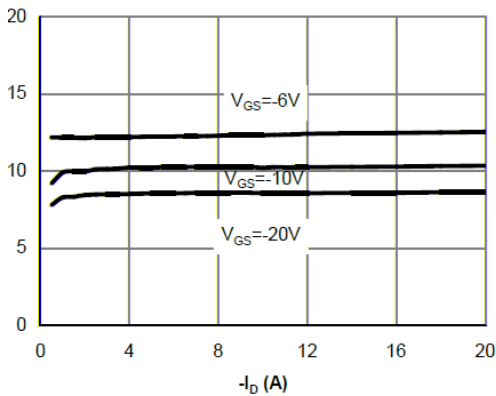


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

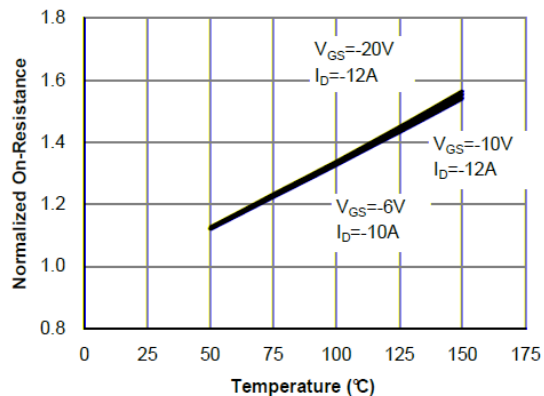


Figure 4: On-Resistance vs. Junction Temperature

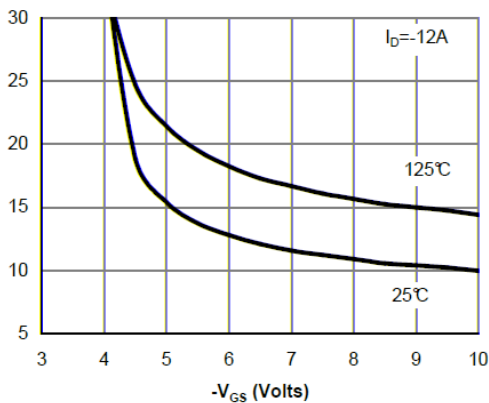


Figure 5: On-Resistance vs. Gate-Source Voltage

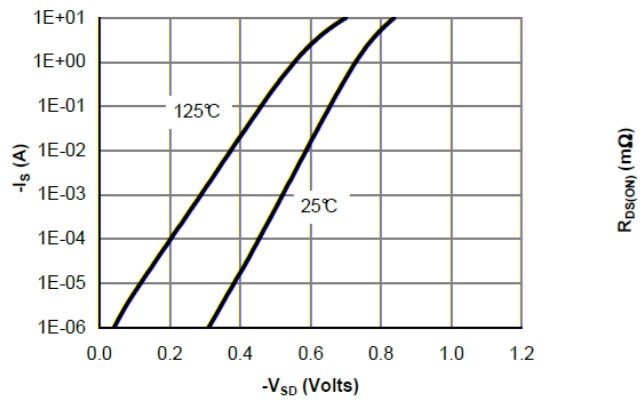


Figure 6: On-Resistance vs. Drain-Source Voltage

TYPICAL CHARACTERISTICS

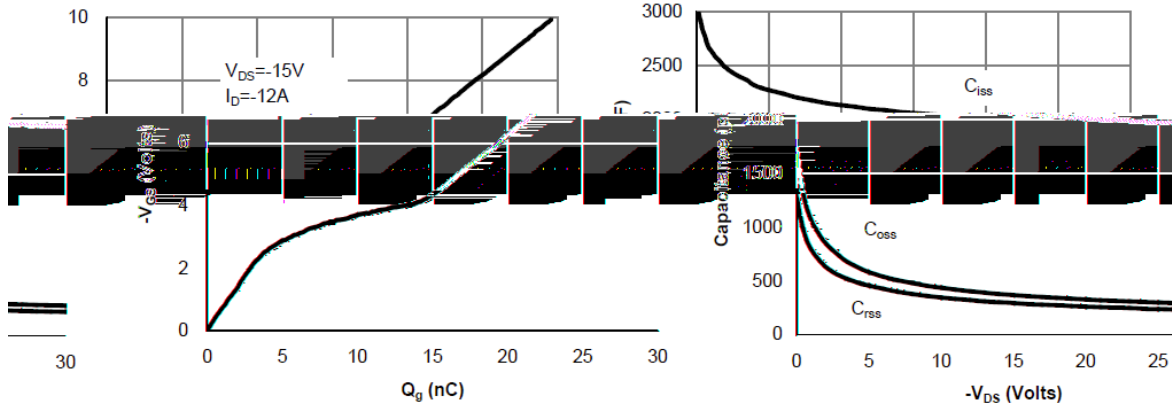


Figure 7: Gate-Charge Characteristics

Figure 8: Capacitance Characteristics

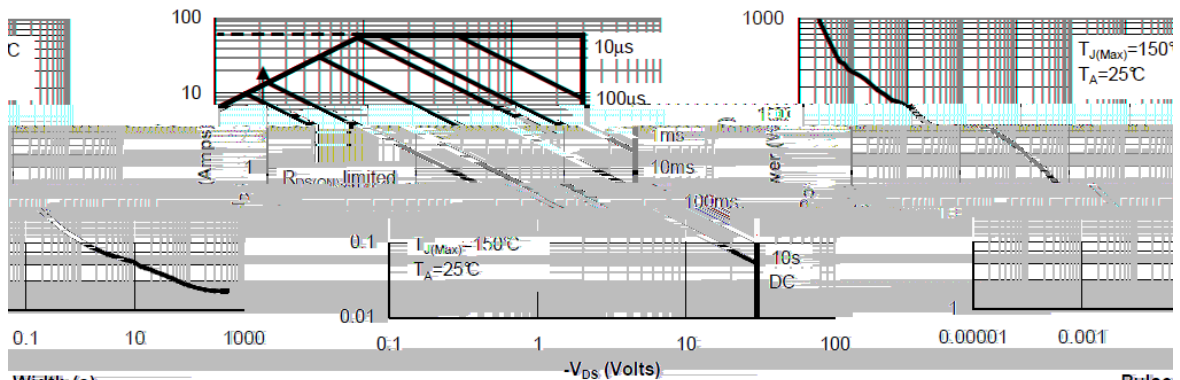


Figure 9: Maximum Forward Biased Safe Operating Area (Note E)

Figure 10: Single Pulse to-Ambient Temperature Rise Characteristics

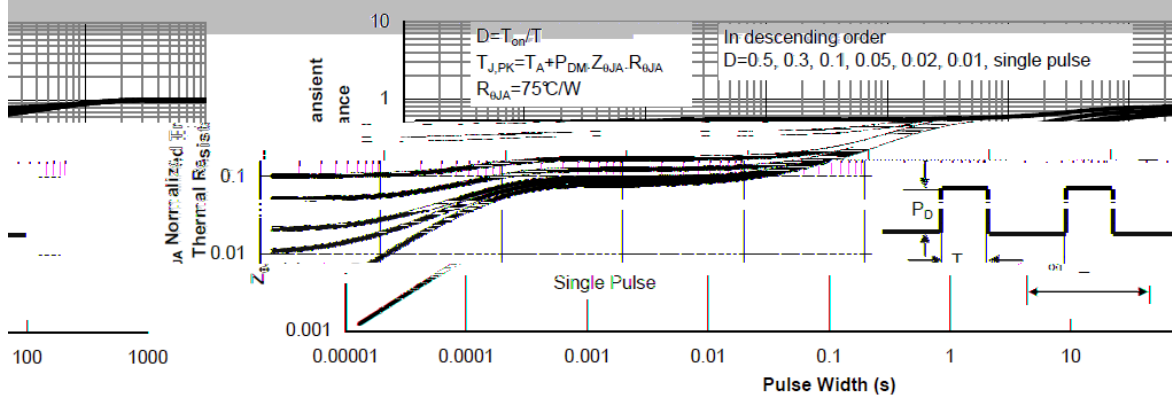
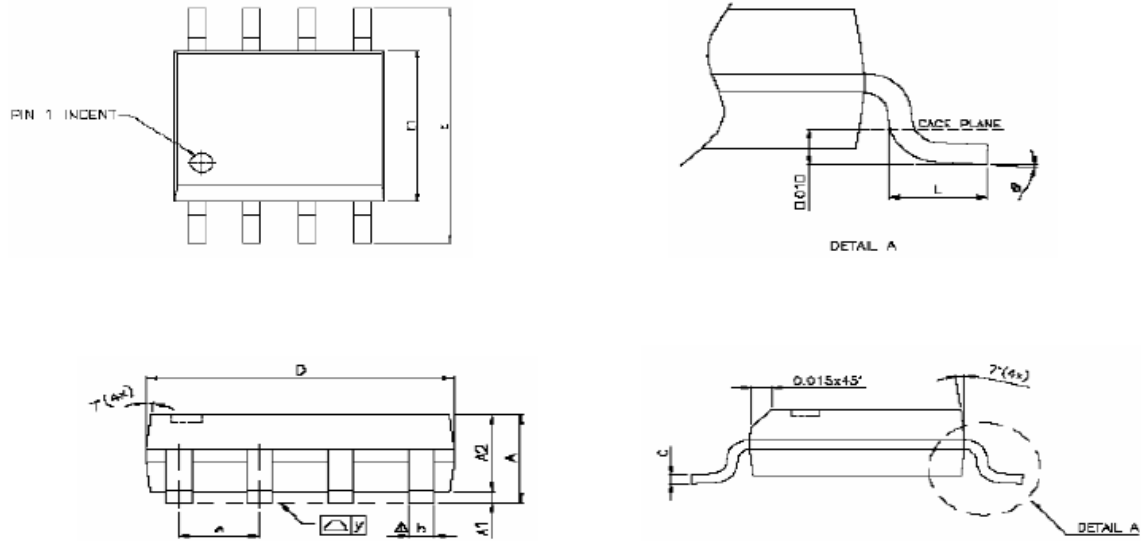


Figure 11: Normalized Maximum Transient Thermal Impedance (Note E)

PACKAGE OUTLINE SOP-8P



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.47	1.60	1.73	0.060	0.063	0.068
B	1.27	1.27	1.27	0.050	0.050	0.050
C	0.25	0.25	0.25	0.010	0.010	0.010
D	4.83	4.83	4.83	0.190	0.190	0.190
E	6.00	6.20	6.30	0.236	0.244	0.250
E1	5.50	4.60	4.50	0.217	0.181	0.177
e	1.27	—	—	0.050	—	—
L	0.71	1.27	0.015	0.028	0.050	—
y	—	0.076	—	—	0.003	—
theta	—	8°	9°	—	8°	—